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[Vishay/Siliconix](#)
[SI7904DN-T1-E3](#)

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Si7904DN

Vishay Siliconix

Dual N-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)
20	0.030 at $V_{GS} = 4.5$ V	7.7
	0.036 at $V_{GS} = 2.5$ V	7.0
	0.045 at $V_{GS} = 1.8$ V	6.3

FEATURES

- Halogen-free Option Available
- TrenchFET® Power MOSFETs: 1.8 V Rated
- New Low Thermal Resistance PowerPAK® Package with Low 1.07 mm Profile

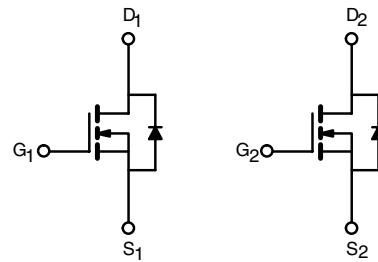
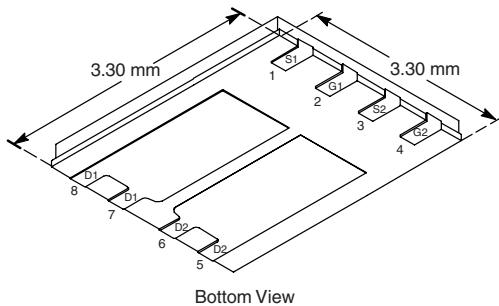


RoHS
COMPLIANT

APPLICATIONS

- HDD Spindle Drive

PowerPAK 1212-8



Ordering Information: Si7904DN-T1-E3 (Lead (Pb)-free)
Si7904DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

N-Channel MOSFET

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

Parameter	Symbol	10 s	Steady State	Unit
Drain-Source Voltage	V_{DS}	20	± 8	V
Gate-Source Voltage	V_{GS}			
Continuous Drain Current ($T_J = 150$ °C) ^a	I_D	7.7	5.3	A
		5.5	3.8	
Pulsed Drain Current	I_{DM}	20		A
Continuous Source Current (Diode Conduction) ^a	I_S	2.3	1.1	
Single Pulse Avalanche Current	I_{AS}	15		mJ
Avalanche Energy	E_{AS}	11		
Maximum Power Dissipation ^a	P_D	2.8	1.3	W
		1.5	0.85	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150		°C
Soldering Recommendations ^{b,c}		260		

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	R_{thJA}	35	44	°C/W
		75	94	
Maximum Junction-to-Case	R_{thJC}	4	5	

Notes:

- Surface Mounted on 1" x 1" FR4 board.
- See Solder Profile (<http://www.vishay.com/ppg?73257>). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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SPECIFICATIONS $T_J = 25^\circ\text{C}$, unless otherwise noted

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Gate Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}$, $I_D = 935 \mu\text{A}$	0.45		1.0	V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}$, $V_{GS} = \pm 8 \text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20 \text{ V}$, $V_{GS} = 0 \text{ V}$		1		
		$V_{DS} = 20 \text{ V}$, $V_{GS} = 0 \text{ V}$, $T_J = 85^\circ\text{C}$		5		μA
On-State Drain Current ^a	$I_{D(\text{on})}$	$V_{DS} \geq 5 \text{ V}$, $V_{GS} = 4.5 \text{ V}$	20			A
Drain-Source On-State Resistance ^a	$R_{DS(\text{on})}$	$V_{GS} = 4.5 \text{ V}$, $I_D = 7.7 \text{ A}$		0.025	0.030	
		$V_{GS} = 2.5 \text{ V}$, $I_D = 7.0 \text{ A}$		0.030	0.036	Ω
		$V_{GS} = 1.8 \text{ V}$, $I_D = 1 \text{ A}$		0.037	0.045	
Forward Transconductance ^a	g_{fs}	$V_{DS} = 10 \text{ V}$, $I_D = 7.7 \text{ A}$		23		S
Diode Forward Voltage ^a	V_{SD}	$I_S = 2.3 \text{ A}$, $V_{GS} = 0 \text{ V}$		0.70	1.2	V
Dynamic^b						
Total Gate Charge	Q_g	$V_{DS} = 10 \text{ V}$, $V_{GS} = 4.5 \text{ V}$, $I_D = 7.7 \text{ A}$		10.2	15	nC
Gate-Source Charge	Q_{gs}			1.3		
Gate-Drain Charge	Q_{gd}			2.4		
Turn-On Delay Time	$t_{d(\text{on})}$	$V_{DD} = 10 \text{ V}$, $R_L = 10 \Omega$ $I_D \approx 1 \text{ A}$, $V_{GEN} = 4.5 \text{ V}$, $R_G = 6 \Omega$		15	23	ns
Rise Time	t_r			50	75	
Turn-Off Delay Time	$t_{d(\text{off})}$			60	90	
Fall Time	t_f			45	68	
Source-Drain Reverse Recovery Time	t_{rr}	$I_F = 2.3 \text{ A}$, $dI/dt = 100 \text{ A}/\mu\text{s}$		40	80	

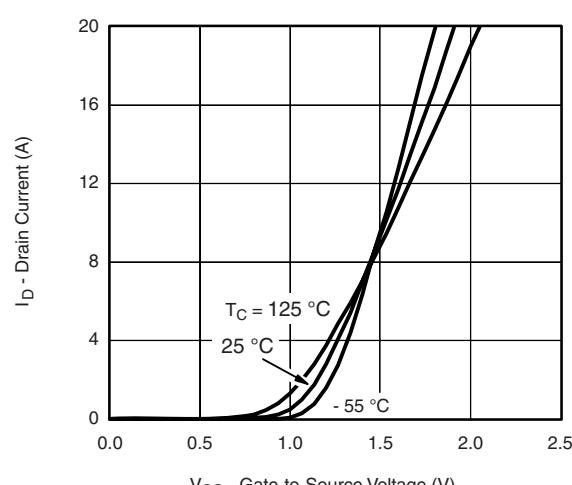
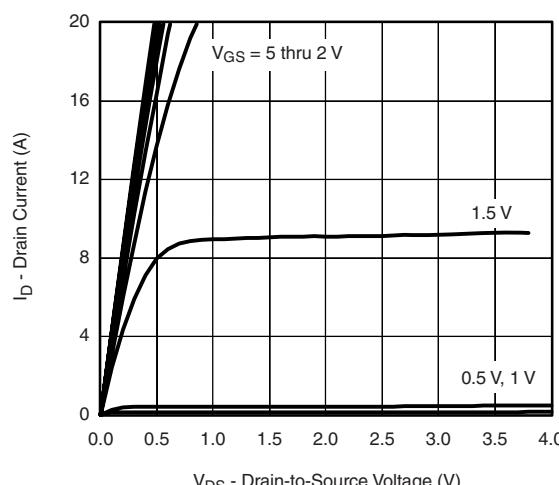
Notes:

a. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2\%$.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, unless otherwise noted

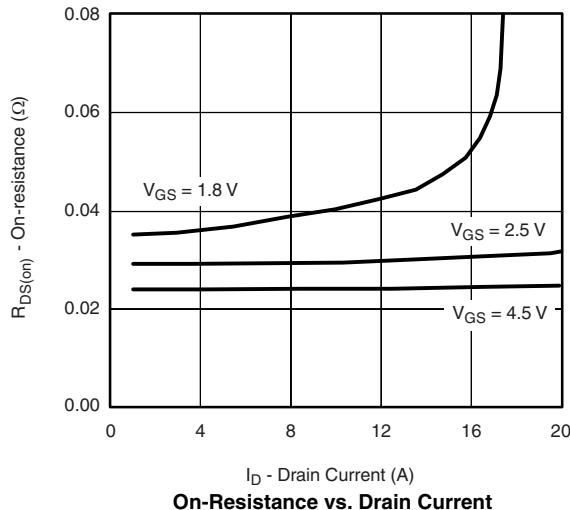




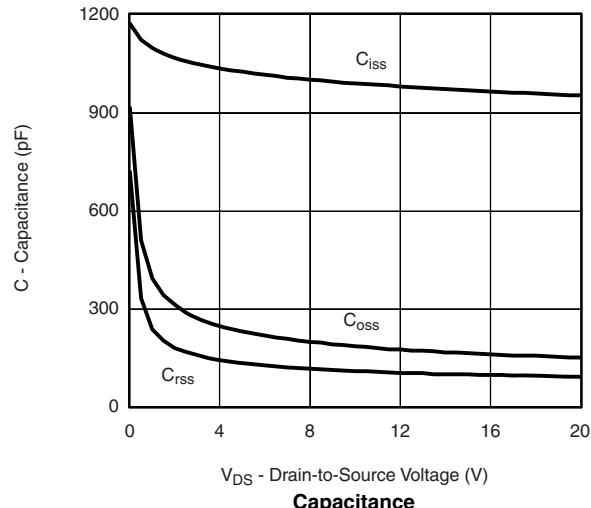
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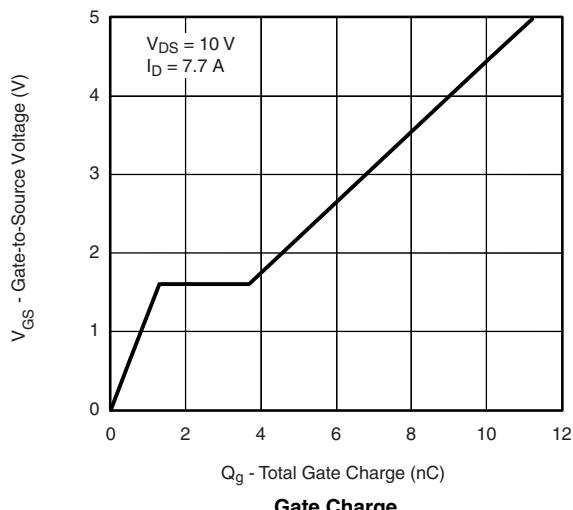
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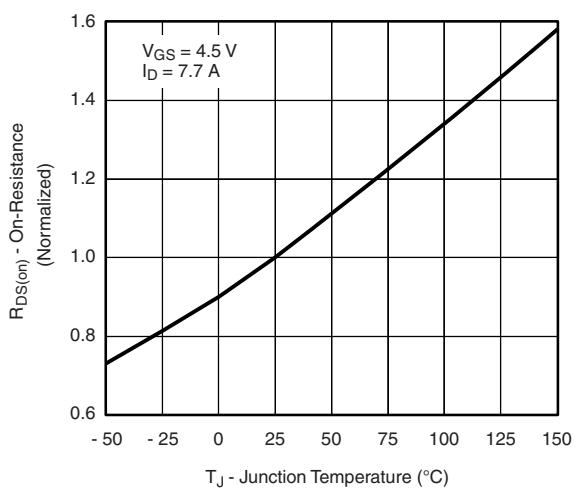
On-Resistance vs. Drain Current



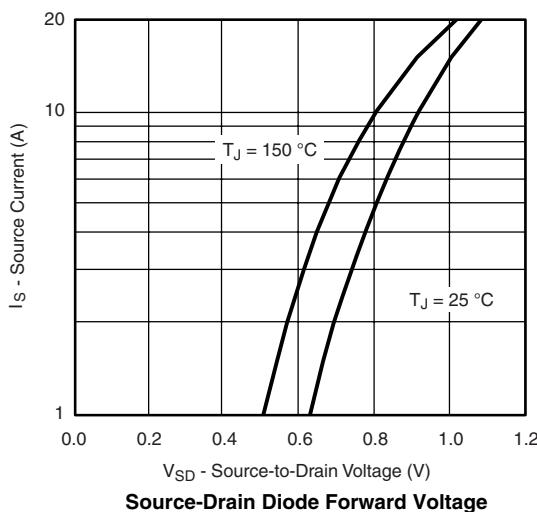
Capacitance



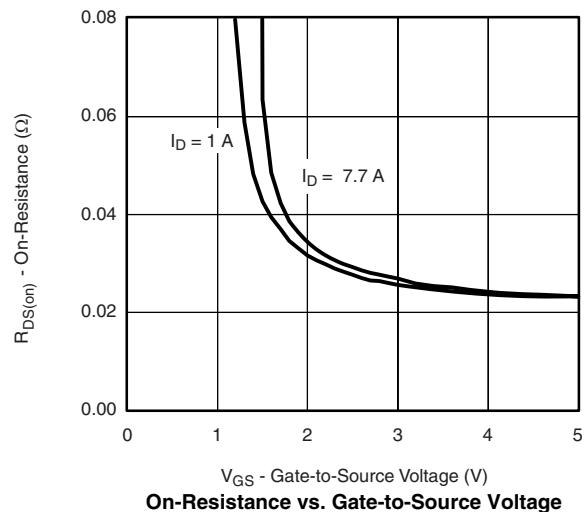
Gate Charge



On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage



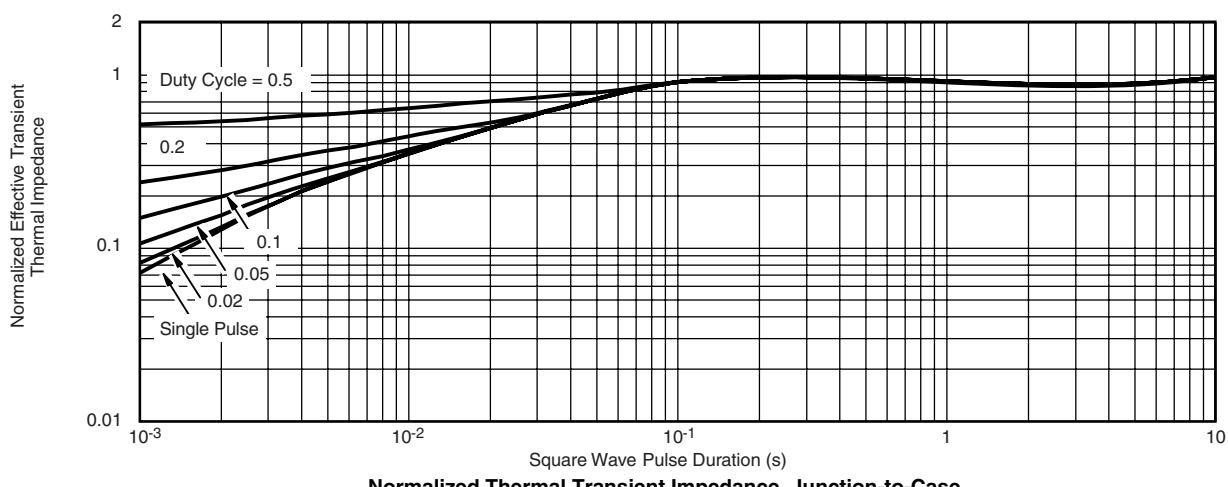
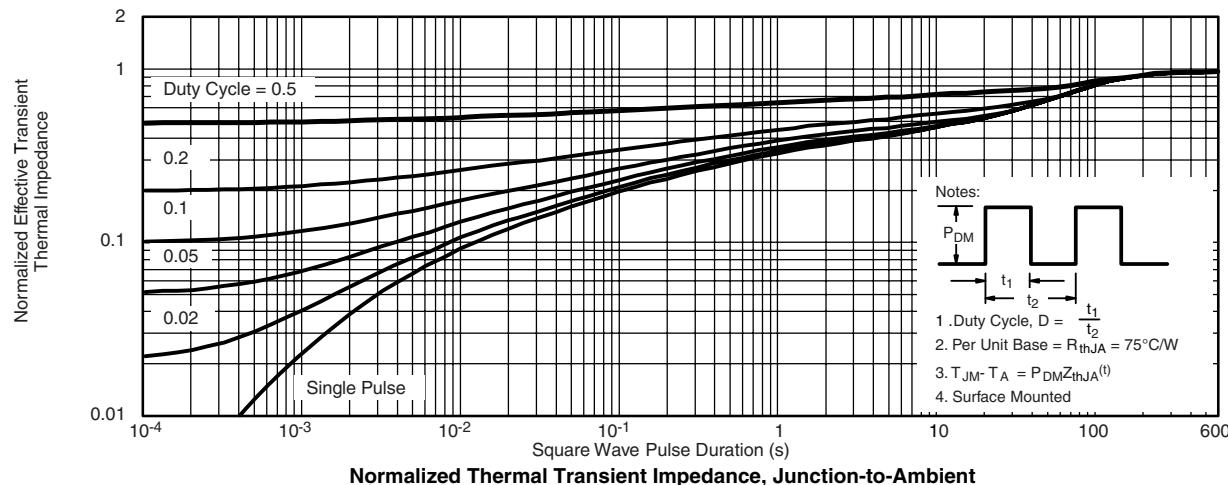
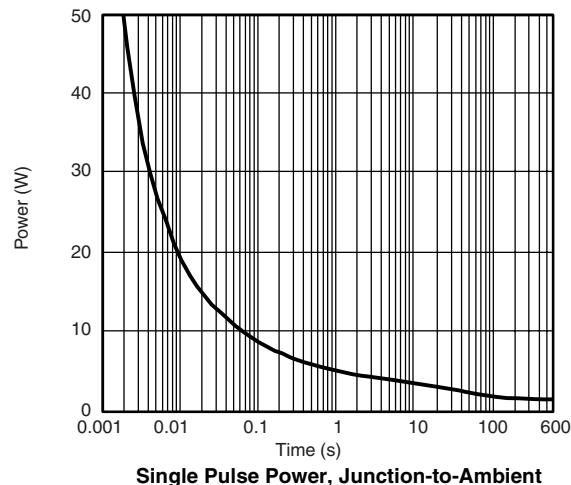
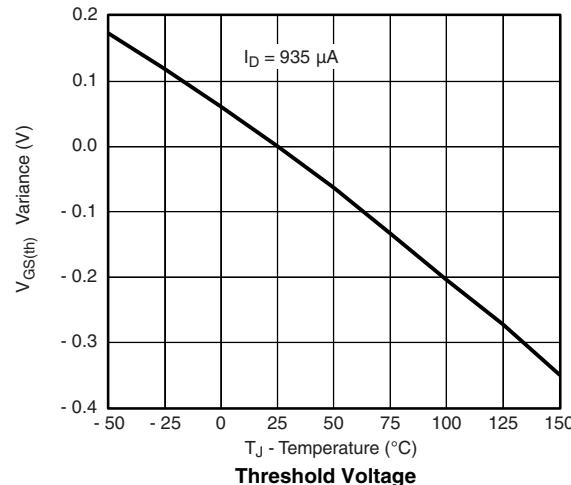
On-Resistance vs. Gate-to-Source Voltage

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